TOSHIBA {DISCRETE/OPTO}

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9097250	TOSHIBA	(DISCRETE	(OPTO)
R S (C) I			

(Hz)

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FET	
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							loss l		Σ	IVfsI TYP,		ບັ	Crss MAX.			ž	NF MAX.	
Application	Type No.	No.	VDS	₽	0	L	VDS	VGS	<u> </u>	VDS	VGS	L	VDS	~	L		٩	
	N-Channel	P-channel	S	(MA)	(mm)	(MA)	ε	ŝ	(sm)	S	(1)	(PF)	ŝ	(ZHW)	(gp)	Ξ	(mA)	51
VHF Amp FM RF	2SK241		20	R	200	1.5~14	10	0	10	10	10	0.05	10	-	3.0	5		[]
		0110		/		0 : 1.5~3.5		Y:3~7 GF	GR : 6~14									
3. µ-X PACKAGE		SERIES					-											
	>> GaAs MES FET		*							1 4 •								
							IDSS		' ∠	IYfsl (1KHz) TYP	z) TYP.		- [NF TYP.		х- л		
Annlication	I YP¢	I ype No.	V _{DS}	<u>_</u>	D		VDS /	VGIS/G2S		VDS	<u>م</u>	VG2S		VDS	u.			
	N-Channet	P-Channel	ε	(WA)	(Mm)	(MA)	S.	2	(mS)	S	(mA)	(S	(qB)	2	(MHz)	•		MV.
UHF RF	3SK121		10	20	200	20~45	ß	0/0	17	വ	10	0	1.5	പ	808			
-	TRANSISTO	SISTOR «				Y : 20~35	10	GR : 30~45	45									- 1
-							hFE		f T	fT TYP. (MIN.)		-	IF MAX	NF MAX, (TYP.)				
Application	Type	Type No.	VCEO	<u>ں</u>	PC		VCE	<u>_</u>		VCE	<u>_</u>		VCC	VAGC	+			
	NPN	ANA	2	(MA)	(MM)		(>)	(mA)	(ZHW)	S	(WW)	(qB)	Ξ	2	(MHz)			
UHF RF Amp	2SC2804	F	20	20	200	25 MIN.	10	2	900	10	2	(3.5)	12	e	800			
UHF OSC. VHF MIX	2SC2805		15	20	200	20 MIN.	e	8	1500	10	8	1	1	ı	1			
VHF OSC.	2SC2806		15	20	200	20 MIN.	e	8	(600)	10	8	1	1	Т	1			
VHF~C Band Low Noise	2SC2876	F	7.5	80	200	30~200	e	50	7000	a	30	(2.3)	ß	I	1000			
UHF MIX OSC Amp	2SC3137		15	20	200	40~200	10	5	2400	10	2	(8)	10	I	800			
VHF MIX	2SC3172		20	20	200	40~300	10	5	1400	10	D.	(3.8)	12	I	200			
: Low Noi	2SC3302		12	70	200	25 MIN.	10	20	5000	10	20	(1.7)	5	I	1000			
UHF OSC NEW	2SC3548		15	8	200	30~200	10	5	4000	10	10	(2.0)	10	I	1000			
UHF RF NEW	2SC3602	R	20	20	200	25 MIN.	10	2	1100	10	2	(3.3)	12	ю	800			
VHF/UHF Low Noise	2SC3608	(12	8	200	30~200	10	20	7000	10	20	(1.1)	10	ы	1000			
a Amp (NEW)	>> MOS FET	=ET ≪																
-		N					lDSS		IYfsl	1Yfsi (1KHz) TYP.	۲₽.		z	NF MAX. (TYP.)	(ТҮР.)			
Application	Түр	Type No.	VDS	<u>0</u>	PD	/	VDS	VG1S/G2S		VDS	٩	VG2S	.	۵۵	f			
	N-Channel P-Chan	P-Channel	ε	(MA)	(MM)	(mA)	1	S	(mS)	ε	(mA)	()	(dB)	ŝ	(ZHM)			
VHF RF Amp	3SK101		20	8	200	3~24*	15	0/4	20	15	10	4	3.2	15	200			
UHF RF Amp	3SK102		8	8	200	3~24*	15	0/4	8 MIN.	15	10	4	5.0	15	800			
VHF RF Amp	3SK114		15	8	200	**9~0	9	C/C	20	9	10	ς ε	(1.4)	9	200			
UHF RF Amp	3SK115		15	g	200	**9~0	9	0/3	17	٥	10	ო	(3.2)	9	808			
UHF RF Amp NEW	3SK145		13.5	30	200	**9~0	9	0/3	16	9	5	~	(2,6)	9	88			
							≻ *	: 3~7 - 9 -	GR : 6~14		BL:12~24		** 0:0~2	0~2	Y : 1~6			